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Table of Contents

Preface: Seventh International Conference on Low-Dimensional Structures and Devices Isaac Hernández-Calderón and Mohamed Henini	1
PHYSICS AND PHYSICS OF MATERIALS	
Ultimate stability of matter: Becoming a particle Raphael Tsu and Timir Datta	3
Electronic properties of graphite in tilted magnetic fields Nataliya A. Goncharuk and Ludvík Smrčka	10
Aberration corrected STEM to study an ancient hair dyeing formula G. Patriarche, E. Van Elslande, J. Castaing, and P. Walter	14
On the bonding nature of electron states for the Fe-Mo double perovskite E. Carvajal, R. Oviedo-Roa, M. Cruz-Irisson, and O. Navarro	18
Total energy study of the microscopic structure and electronic properties of tetragonal perovskite SrTiO₃ A. Rubio-Ponce and D. Olguín	22
Properties of the In₂O₃-Si interface: An <i>ab initio</i> study of a model geometry Benjamin Höffling and Friedhelm Bechstedt	27
Fabrication and characterization of a Au/PMMA/Sb metal-organic insulator-semiconductor junction M. C. Bandeira and J. G. Guimarães	31
Hydrogen and temperature dependence of d.c. pulsed magnetron sputtered amorphous silicon Philipp Schäfer, Frank Nobis, Ovidiu D. Gordan, Hartmut Kupfer, Frank Richter, and Dietrich R. T. Zahn	35
Spatial dependence of polycrystalline FTO's conductance analyzed by conductive atomic force microscope (C-AFM) Alexandre Pessoa Peixoto and J. C. da Costa	39

Fabrication of FCC-SiO₂ colloidal crystals using the vertical convective self-assemble method	
O. A. Castañeda-Uribe, J. C. Salcedo-Reyes, H. A. Méndez-Pinzón, and A. M. Pedroza-Rodríguez	43
Fabrication and characterization of nanometric SiO_x/SiO_y multilayer structures obtained by LPCVD	
S. Román-López, M. Aceves-Mijares, J. Carrillo-López, and J. Pedraza-Chávez	47
Synthesis and characterization of SnO₂ thin films doped with Fe to 10%	
E. López, J. Marín, and J. Osorio	51
Propagation of Dirac electrons in Cantor graphene multilayers	
R. Rodríguez-González, J. C. Martínez-Orozco, J. Madrigal-Melchor, and I. Rodríguez-Vargas	55
QUANTUM DOTS AND QUANTUM RING	
Recent developments in droplet epitaxy	
Takaaki Mano, Masafumi Jo, Takashi Kuroda, Marco Abbarchi, Takeshi Noda, and Kazuaki Sakoda	61
Self-assembly of triangular quantum dots on (111)A substrates by droplet epitaxy	
M. Jo, T. Mano, M. Abbarchi, T. Kuroda, and K. Sakoda	71
Site control technique for quantum dots using electron beam induced deposition	
Kanji Iizuka, JaeHun Jung, and Hiroshi Yokota	75
To the understanding of the formation of the droplet-epitaxial III-V based nanostructures	
Ákos Nemesics	79
Quantum rings of non-uniform thickness in magnetic field	
F. A. Rodríguez-Prada, L. F. García, and I. D. Mikhailov	83
Power-law photoluminescence decay in quantum dots	
Karel Král and Miroslav Menšík	87
Local droplet etching – Nanoholes, quantum dots, and air-gap heterostructures	
Ch. Heyn, D. Sonnenberg, A. Graf, J. Kerbst, A. Stemann, and W. Hansen	91
Energy levels and far-infrared spectra of oval-shaped nanorings	
W. Gutiérrez, L. F. García, and I. D. Mikhailov	95
Neutral and positively charged excitons in narrow quantum ring	
L. C. Porras Monroy, F. A. Rodríguez-Prada, and I. D. Mikhailov	99

1D SYSTEMS AND NANOWIRES

Physical properties and applications of $\text{In}_x\text{Ga}_{1-x}\text{N}$ nanowires

J. Segura-Ruiz, M. Gómez-Gómez, N. Garro, G. Martínez-Criado, A. Cantarero, C. Denker, J. Malindretos, and A. Rizzi 103

Electronic states of lithium passivated germanium nanowires: An *ab-initio* study

A. Trejo, E. Carvajal, R. Vázquez-Medina, and M. Cruz-Irisson 114

Growth and properties of core-shell GaP/ZnO nanowires

J. Novák, P. Eliáš, S. Hasenöhr, I. Vávra, Z. Križanová, I. Novotný, and J. Kováč 118

Study of spin-polaron formation in 1D systems

Y. Arredondo, E. Vallejo, and O. Navarro 122

QUANTUM WELLS

Evaluation of electron mobility in InSb quantum wells by means of percentage-impact

T. D. Mishima, M. Edirisooriya, and M. B. Santos 126

Nitrogen-concentration control in GaNAs/AlGaAs quantum wells using nitrogen δ -doping technique

Takaaki Mano, Masafumi Jo, Takashi Kuroda, Martin Elborg, Takeshi Noda, Yoshimasa Sugimoto, Yoshiki Sakuma, and Kazuaki Sakoda 130

Photoluminescence study of the substitution of Cd by Zn during the growth by atomic layer epitaxy of alternate CdSe and ZnSe monolayers

I. Hernández-Calderón and J. C. Salcedo-Reyes 134

Selfsimilar and fractal analysis of n-type delta-doped quasiregular GaAs quantum wells

H. García-Cervantes and I. Rodríguez-Vargas 138

Sensitivity of absorption spectra to surface segregation in InGaN/GaN quantum well structures

M. V. Klymenko, O. V. Shulika, and I. A. Sukhoivanov 142

A current modulation in the $\text{Gd}_2\text{O}_3/\text{Si}/\text{Gd}_2\text{O}_3$ quantum well structure as a mean to monitor oxygen vacancies

Wattaka Sitaputra, John A. Hudak, and Raphael Tsu 146

Quantum confined Stark effect in Gaussian quantum wells: A tight-binding study

A. Ramírez-Morales, J. C. Martínez-Orozco, and I. Rodríguez-Vargas 150

PHOTONIC CRYSTALS

Characterization of the bistable wideband optical filter on the basis of nonlinear 2D photonic crystal

I. V. Guryev, I. A. Sukhoivanov, J. A. Andrade Lucio, O. Ibarra Manzano, E. Vargaz Rodriguez, D. Claudio Gonzales, R. I. Mata Chavez, and N. S. Gurieva 154

Plasmon-polariton and $\langle n \rangle = 0$ non-Bragg gaps in 1D Cantor photonic superlattices

J. R. Mejía-Salazar, N. Porrás-Montenegro, E. Reyes-Gómez, S. B. Cavalcanti, and L. E. Oliveira 158

PHOTOVOLTAIC STRUCTURES

Catalyst-free, III-V nanowire photovoltaics

D. G. Davies, N. Lambert, P. W. Fry, A. Foster, A. B. Krysa, and L. R. Wilson 162

Dilute antimonide nitride for long wavelength infrared photodetection

X. Z. Chen, Y. J. Jin, and D. H. Zhang 166

Spectral photoresponse of ZnSe/GaAs(001) heterostructures with CdSe ultra-thin quantum well insertions

D. A. Valverde-Chávez, F. Sutara, and I. Hernández-Calderón 171

Hetero-structure p-i-n solar cell with high efficiency

S. Mil'shtein, A. Pillai, D. P. Nair, and A. Karumuri 175

Hetero-structure p-i-n-i-p solar cell with virtual collector

R. Kwende, A. Pillai, and S. Mil'shtein 178

Selective p-i-n photodetector with resonant tunneling

S. Mil'shtein, S. Wilson, and A. Pillai 181

DEVICES

Low dimension structures and devices for new generation photonic technology

D. H. Zhang, D. Y. Tang, T. P. Chen, T. Mei, and X. C. Yuan 185

Donor bound excitons in ZnSe nanoresonators - Applications in quantum information science

A. Pawlis, K. Lischka, K. Sanaka, D. Sleiter, and Y. Yamamoto 194

Room-temperature nonlinear transport phenomena in low-dimensional Ni-Nb-Zr-H glassy alloys and its device

Mikio Fukuhara and Hajime Yoshida 205

Digital noise generators using one-dimensional chaotic maps	
J. A. Martínez-Ñonthe, L. Palacios-Luengas, M. Cruz-Irisson, J. A. Díaz Méndez, and R. Vazquez Medina	210
A single-electron tunneling reset-set flip-flop	
Bianca M. S. M. de Alencar and Janaina G. Guimarães	214
AC-magnetotransport of a 2DEG in the quantum Hall regime	
C. Hernández and C. Chaubet	218
Electronic structure computation and differential capacitance profile in δ-doped FET as a function of hydrostatic pressure	
C. Carlos-Pinedo, I. Rodríguez-Vargas, and J. C. Martínez-Orozco	222
Off state breakdown behavior of AlGaAs / InGaAs field plate pHEMTs	
John Palma and Samson Mil'shtein	225
Auto-associative nanoelectronic neural network	
C. P. S. M. Nogueira and J. G. Guimarães	229
Author Index	233